UHF power LDMOS transistor Rev. 1 — 17 March 2016

AMMPLEON

Objective data sheet

Product profile 1.

1.1 General description

A 750 W LDMOS RF power transistor for broadcast Doherty transmitter applications. The excellent ruggedness of this device makes it ideal for digital and analog transmitter applications.

Table 1. **Application information**

RF performance at V_{DS} = 50 V in an asymmetrical Doherty application.

Test signal	f	P _{L(AV)}	Gp	η_{D}	IMD _{shldr}	PAR
	(MHz)	(W)	(dB)	(%)	(dBc)	(dB)
DVB-T (8k OFDM)	470 to 590	150	17	52	-38	8 [1]
	580 to 690	<tbd></tbd>	<tbd></tbd>	<tbd></tbd>	<tbd></tbd>	<tbd></tbd>
	650 to 790	150	15	49	-38	8 [1]

^[1] PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.

1.2 Features and benefits

- Designed for asymmetric Doherty operation
- High efficiency
- Integrated ESD protection
- Excellent ruggedness
- High power gain
- Excellent reliability
- Easy power control
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Broadcast transmitter applications in the UHF band
- Digital broadcasting

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outl	ine Graphic symbol
BLF888E	(SOT539A)		
1	drain1 (peak)		
2	drain2 (main)	1 2	1
3	gate1 (peak)		<u> </u>
4	gate2 (main)	3 4	3——5
5	source	[1]	4 —
			' ⊢¬
			2 sym117
BLF888E	ES (SOT539B)		
1	drain1 (peak)		
2	drain2 (main)	1 2	1
3	gate1 (peak)		 5
4	gate2 (main)	3 4	3 — 5
5	source	[1]	4
			ľ
			2 sym117
			-

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Packag	^a ckage			
	Name	Description	Version		
BLF888E	-	flanged balanced ceramic package; 2 mounting holes; 4 leads	SOT539A		
BLF888ES	-	earless flanged balanced ceramic package; 4 leads	SOT539B		

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS(amp)main}$	main amplifier drain-source voltage		-	104	٧
$V_{DS(amp)peak}$	peak amplifier drain-source voltage		-	120	V
$V_{GS(amp)main}$	main amplifier gate-source voltage		-0.5	+11	V
$V_{GS(amp)peak}$	peak amplifier gate-source voltage		-6	+11	٧
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature	[1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

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Thermal characteristics **5**.

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	$T_{case} = 80 ^{\circ}C; P_{L} = 150 W$	11 <tbd></tbd>	K/W

^[1] $R_{th(j-c)}$ is measured under RF conditions.

Characteristics 6.

Table 6. **DC** characteristics

 T_i = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Main dev	ice					
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 2.4 \text{ mA}$	104	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V _{DS} = 10 V; I _D = 240 mA	1.4	1.9	2.4	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 50 V	-	-	2.8	μА
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	38	-	Α
I _{GSS}	gate leakage current	V _{GS} = 10 V; V _{DS} = 0 V	-	-	280	nA
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 8.5 \text{ A}$	-	120	-	mΩ
Peak dev	ice					
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 3.6 \text{ mA}$	120	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V _{DS} = 10 V; I _D = 360 mA	1.4	1.9	2.4	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 50 V	-	-	2.8	μА
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	57	-	Α
I _{GSS}	gate leakage current	V _{GS} = 10 V; V _{DS} = 0 V	-	-	280	nA
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 12.6 \text{ A}$	-	90	-	mΩ

Table 7. **AC** characteristics

 T_i = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
Main device							
C _{iss}	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	210	-	pF	
Coss	output capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	67	-	pF	
C _{rss}	reverse transfer capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	1.35	-	pF	
Peak dev	Peak device						
C _{iss}	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	315	-	pF	
Coss	output capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	105	-	pF	
C _{rss}	reverse transfer capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	1.5	-	pF	

Table 8. RF characteristics

RF characteristics in Ampleon production test circuit, $T_{case} = 25$ °C; unless otherwise specified.

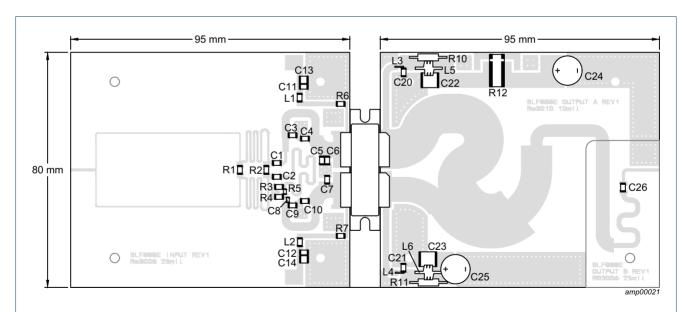
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
DVB-T (8	k OFDM), class-AB					
V_{DS}	drain-source voltage		-	50	-	V
I_{Dq}	quiescent drain current	peak section: V _{GS} = 1.3 V below V _{GS(th)} (peak)	-	600	-	mA
$P_{L(AV)}$	average output power	f = 550 MHz	-	150	-	W
Gp	power gain	f = 550 MHz	15.3	17	-	dB
η_{D}	drain efficiency	f = 550 MHz	47	52	-	%
IMD_{shldr}	intermodulation distortion shoulder	f = 550 MHz	-	-24	-21	dBc
PAR	peak-to-average ratio	f = 550 MHz	-	7.8	-	dB

7. Test information

7.1 Ruggedness in Doherty operation

The BLF888E and BLF888ES are capable of withstanding a load mismatch corresponding to VSWR \geq <tbd> through all phases under the following conditions: V_{DS} = <tbd> V; f = <tbd> MHz at rated load power.

7.2 Test circuit



Printed-Circuit Board (PCB): Rogers 3006; ε_r = 6.5 F/m; height = 0.635 mm; Cu (top/bottom metalization); thickness copper plating = 29.6 μ m; Rogers 3010: ε_r = 10 F/m; height = 0.254 mm

See Table 9 for a list of components.

Fig 1. Component layout for production RF test circuit

Table 9. List of components For test circuit see Figure 1.

Component	Description	Value	Remarks
C1, C2	multilayer ceramic chip capacitor	51 pF [1	ATC 100B
C3	multilayer ceramic chip capacitor	11 pF [1	ATC 100B
C4	multilayer ceramic chip capacitor	13 pF [1	ATC 100B
C5, C6	multilayer ceramic chip capacitor	24 pF [1	ATC 100B
C7	multilayer ceramic chip capacitor	33 pF <u>[1</u>	ATC 100B
C8	multilayer ceramic chip capacitor	51 pF [2	ATC 100A
C9	multilayer ceramic chip capacitor	12 pF [1	ATC 100B
C10	multilayer ceramic chip capacitor	20 pF [1	ATC 100B
C11, C12	multilayer ceramic chip capacitor	43 pF [1	ATC 100B
C13, C14	multilayer ceramic chip capacitor	4.7 μF	
C20, C21	electrolytic capacitor	100 pF <u>[1</u>	ATC 100B
C22, C23	multilayer ceramic chip capacitor	4.7 μF, 100 V	
C25, C25	electrolytic capacitor	470 μF, 63 V	
C26	multilayer ceramic chip capacitor	47 pF [1	ATC 100B
L1, L2	inductor	10 nH	Coilcraft
L3, L4	inductor	0.5 turn, D = 2 mm, d = 1mm	
L5, L6	inductor	1 turn, D = 5 mm, d = 1mm	
R1	chip resistor	90 Ω	
R2	chip resistor	265 Ω	
R3, R4	chip resistor	360 Ω	
R5	chip resistor	15 Ω	
R6	chip resistor	75 Ω	
R7	chip resistor	5 Ω	
R10, R11	wire resistor	1 Ω	
R12	shunt resistor	0.01 Ω	

^[1] American Technical Ceramics type 100B or capacitor of same quality

^[2] American Technical Ceramics type 100A or capacitor of same quality

8. Package outline

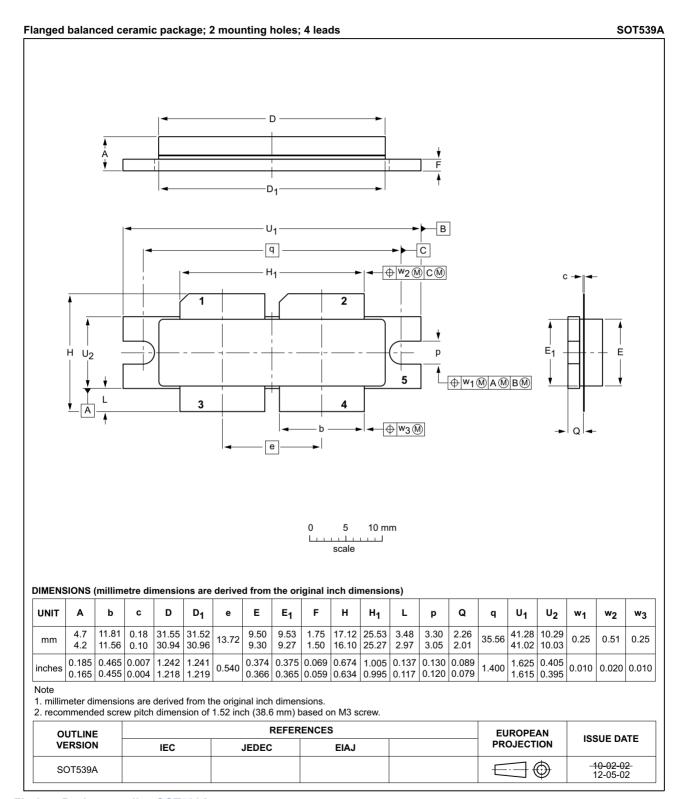


Fig 2. Package outline SOT539A

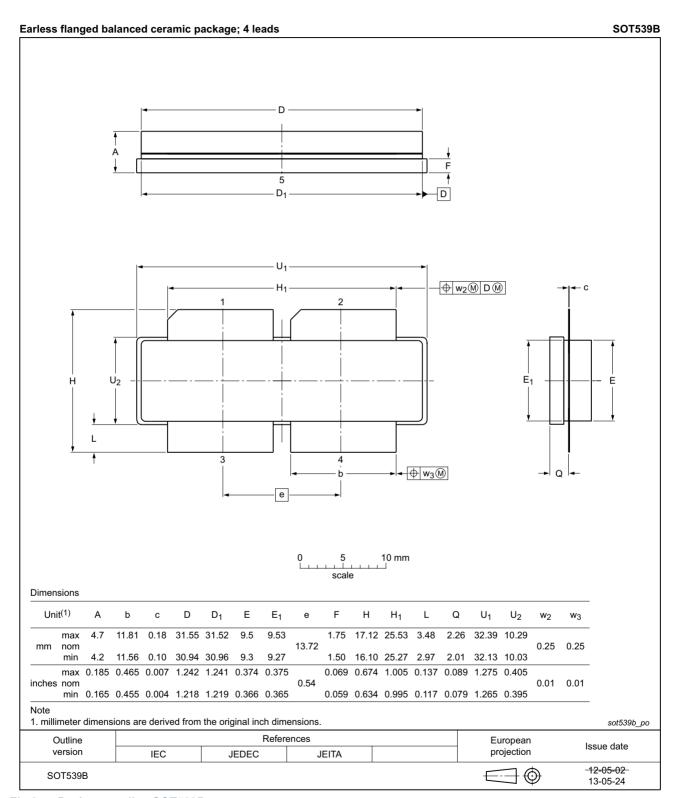


Fig 3. Package outline SOT539B

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9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

Acronym	Description	
CCDF	Complementary Cumulative Distribution Function	
DVB-T	Digital Video Broadcast - Terrestrial	
ESD	ElectroStatic Discharge	
LDMOS	Laterally Diffused Metal-Oxide Semiconductor	
MTF	Median Time to Failure	
OFDM	Orthogonal Frequency Division Multiplexing	
PAR	Peak-to-Average Ratio	
VSWR	Voltage Standing Wave Ratio	
UHF	Ultra High Frequency	

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF888E_BLF888ES v.1	20160317	Objective data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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